NSN 5961-01-252-8713

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-252-8713 **Inclosure Material:** Metal **Overall Length:** 0.710 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.187 inches **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 20.0 regulator voltage **Current Rating Per Characteristic:** 120.00 milliamperes voltage regulator diode current **Power Rating Per Characteristic:** 10.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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